

P10B28HP2

Power MOSFETs  
280V, 10A, N-channel

Feature

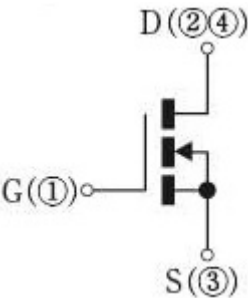
- N-channel
- SMD
- High Voltage
- Low Capacitance
- High Avalanche Durability, High di/dt Durability
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): FB  
Package (JEDEC Code): TO-252AA



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

| Item                              | Symbol           | Conditions                   | Ratings    | Unit |
|-----------------------------------|------------------|------------------------------|------------|------|
| Storage temperature               | Tstg             |                              | -55 to 150 | °C   |
| Channel tempertature              | Tch              |                              | 150        | °C   |
| Drain-source voltage              | V <sub>DSS</sub> |                              | 280        | V    |
| Gate-source voltage               | V <sub>GSS</sub> |                              | ±30        | V    |
| Continuous drain current(DC)      | I <sub>D</sub>   |                              | 10         | A    |
| Continuous drain current(Peak)    | I <sub>DP</sub>  | Pulse width 10μs, duty=1/100 | 40         | A    |
| Continuous source current(DC)     | I <sub>S</sub>   |                              | 10         | A    |
| Total power dissipation           | P <sub>T</sub>   |                              | 70         | W    |
| Repetitive avalanche current      | I <sub>AR</sub>  | Starting Tch=25°C Tch≤150°C  | 10         | A    |
| Single avalanche energy           | E <sub>AS</sub>  | Starting Tch=25°C Tch≤150°C  | 50         | mJ   |
| Repetitive avalanche energy       | E <sub>AR</sub>  | Starting Tch=25°C Tch≤150°C  | 5          | mJ   |
| Drain-source diode di/dt strength | di/dt            | I <sub>S</sub> =10A, Tc=25°C | 350        | A/μs |

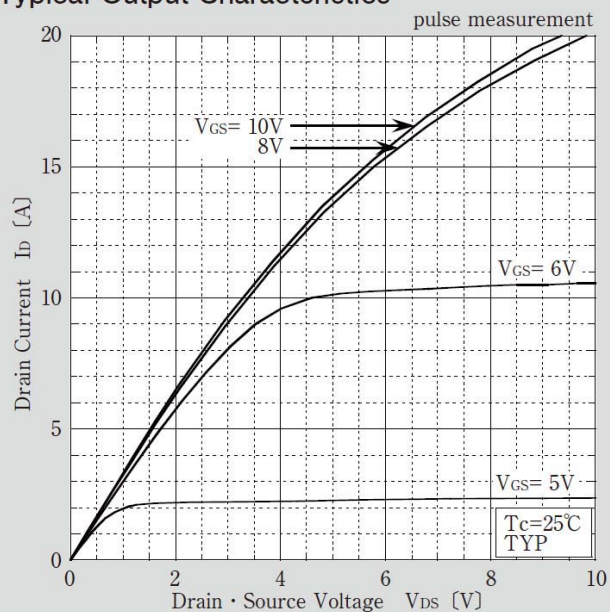
※ :See the original Specifications

**Electrical Characteristics** (unless otherwise specified : Tc=25°C)

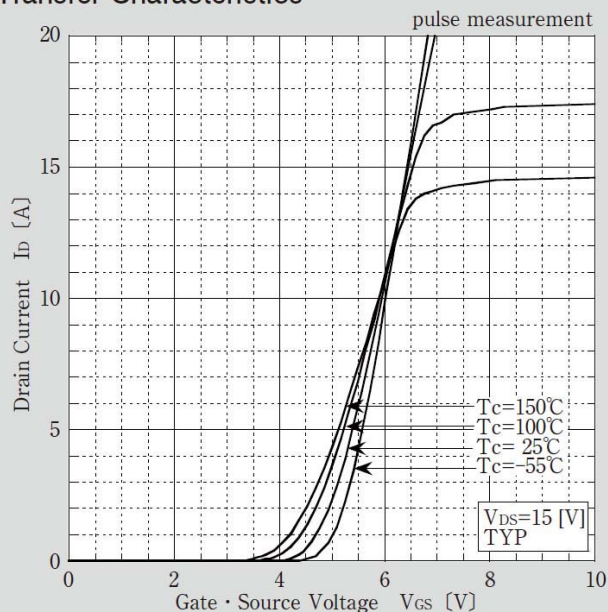
| Item                                    | Symbol        | Conditions   | Ratings |      |      | Unit |
|---|---------------|--|---------|------|------|------|
|   |               |  | MIN     | TYP  | MAX  |      |
| Drain-Source breakdown voltage          | $V_{(BR)DSS}$ | ID=1mA, VGS=0V   | 280     |      |      | V    |
| Zero gate voltage drain current         | $I_{DSS}$     | VDS=280V, VGS=0V                                       |         |      | 100  | μA   |
| Gate-source leakage current             | $I_{GSS}$     | VGS=±25V, VDS=0V                                       |         |      | ±10  | μA   |
| Forward transconductance                | $g_{fs}$      | ID=5A, VDS=10V   | 3.6     | 7.3  |      | S    |
| Static drain-source on-state resistance | $R_{DS(ON)}$  | ID=5A, VGS=10V   |         | 0.3  | 0.4  | Ω    |
| Gate threshold voltage                  | $V_{th}$      | ID=1mA, VDS=10V  | 3       | 3.75 | 4.5  | V    |
| Source-drain diode forward voltage      | $V_{SD}$      | IS=5A, VGS=0V  |         |      | 1.5  | V    |
| Thermal resistance                      | $R_{th(j-c)}$ | Junction to case                                       |         |      | 1.78 | °C/W |
| Total gate charge                       | $Q_g$         | VDD=200V, VGS=10V, ID=10A                              |         | 11.4 |      | nC   |
| Input capacitance                       | $C_{iss}$     | VDS=50V, VGS=0V, f=1MHz                                |         | 500  |      | pF   |
| Reverse transfer capacitance            | $C_{rss}$     | VDS=50V, VGS=0V, f=1MHz                                |         | 7.2  |      | pF   |
| Output capacitance                      | $C_{oss}$     | VDS=50V, VGS=0V, f=1MHz                                |         | 77   |      | pF   |
| Turn-on delay time                      | $t_{d(on)}$   | ID=5A, RL=30Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V |         | 17   |      | ns   |
| Rise time                               | $t_r$         | ID=5A, RL=30Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V |         | 35   |      | ns   |
| Turn-off delay time                     | $t_{d(off)}$  | ID=5A, RL=30Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V |         | 56   |      | ns   |
| Fall time                               | $t_f$         | ID=5A, RL=30Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V |         | 31   |      | ns   |

※ : See the original Specifications

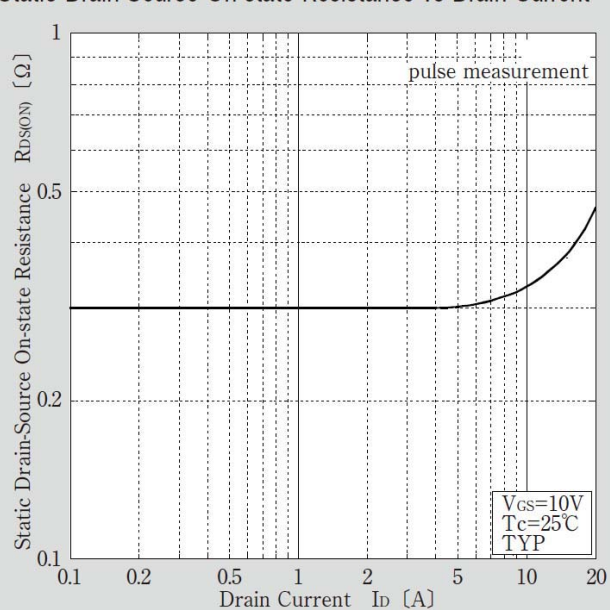
## Typical Output Characteristics



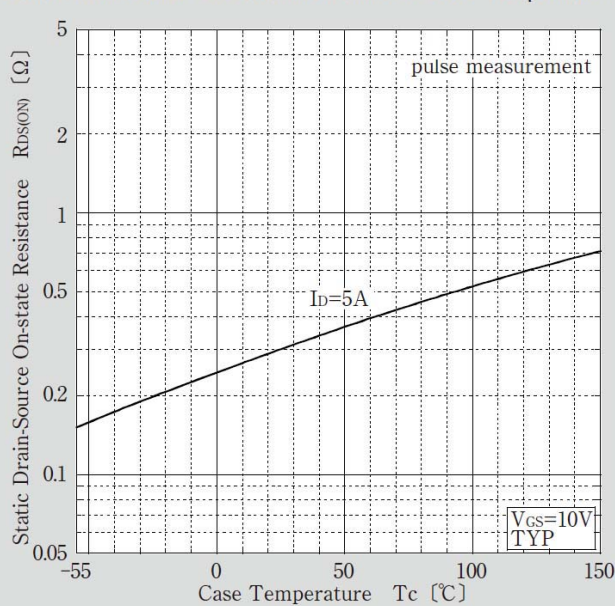
## Transfer Characteristics



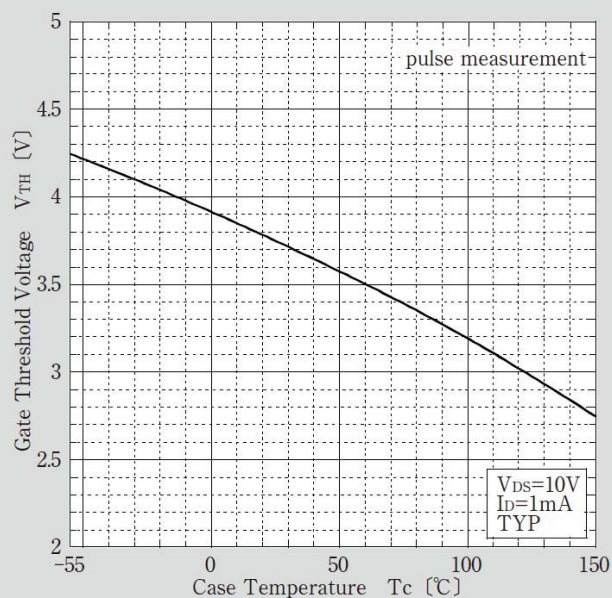
## Static Drain-Source On-state Resistance vs Drain Current



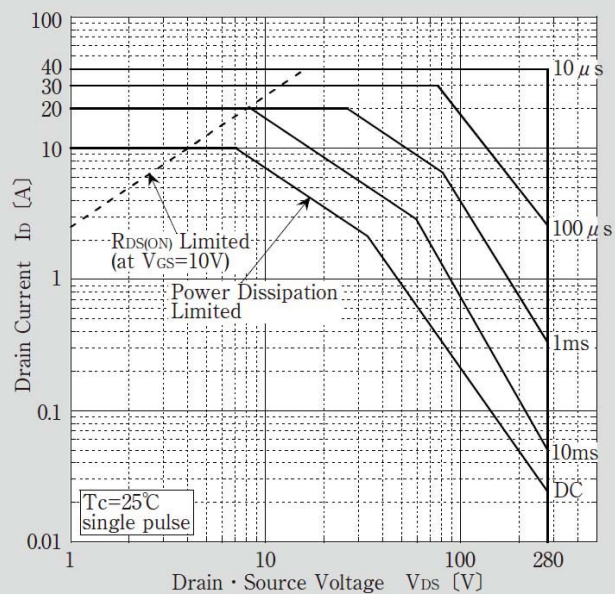
## Static Drain-Source On-state Resistance vs Case Temperature



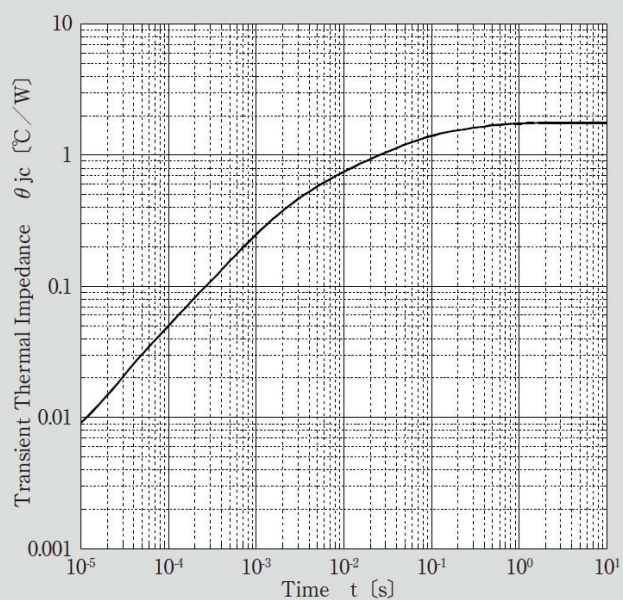
### Gate Threshold Voltage vs Case Temperature



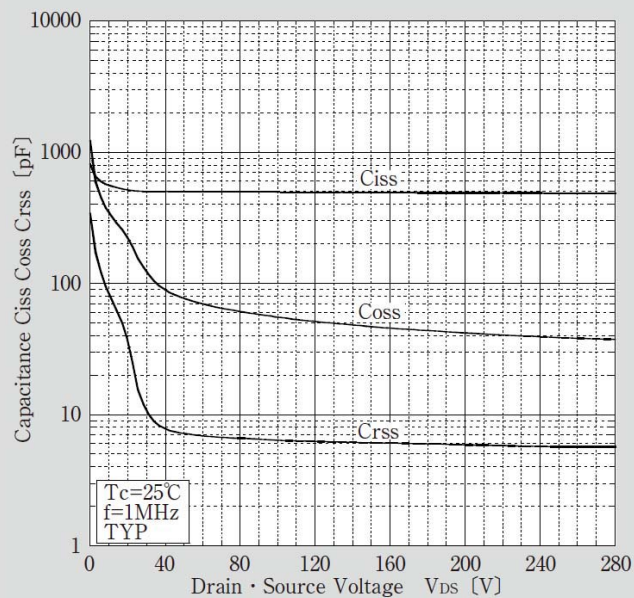
### Safe Operating Area



### Transient Thermal Impedance

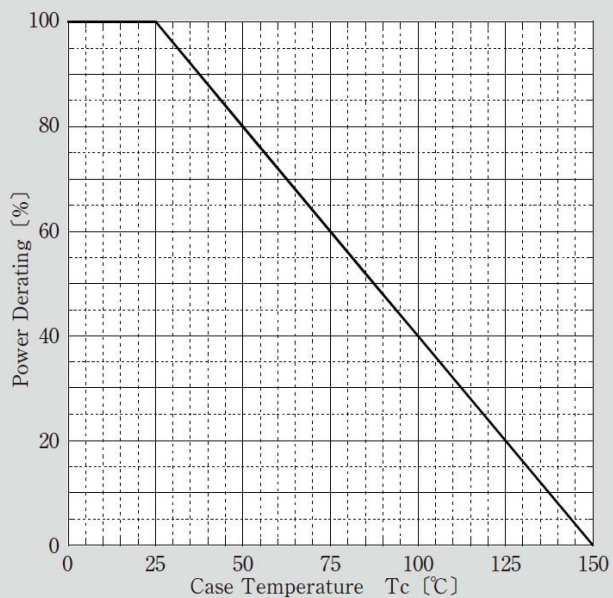


### Capacitance Characteristics

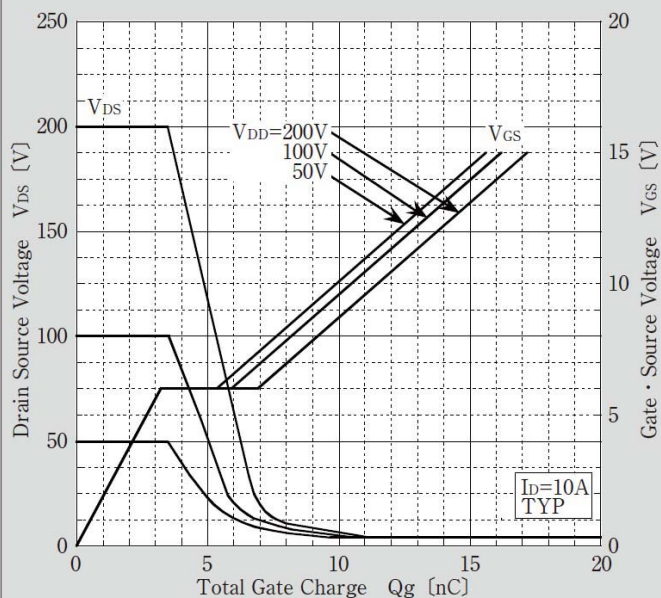




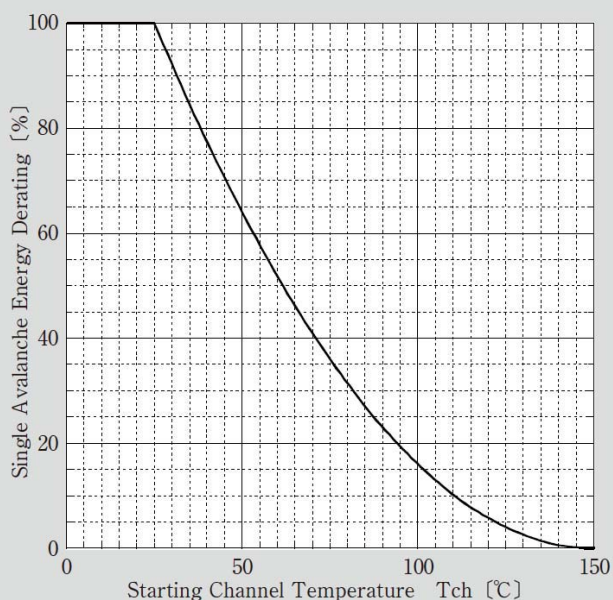
Power Derating - Case Temperature



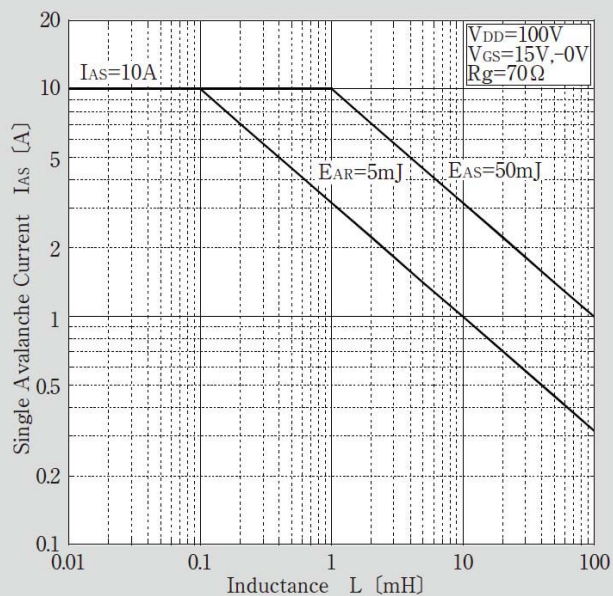
Gate Charge Characteristics



Single Avalanche Energy Derating vs Channel Temperature

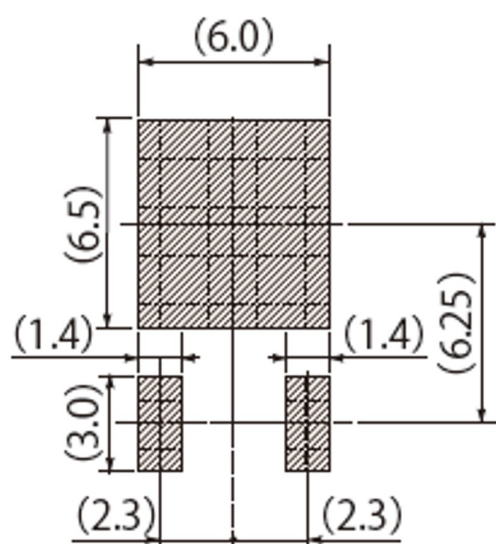
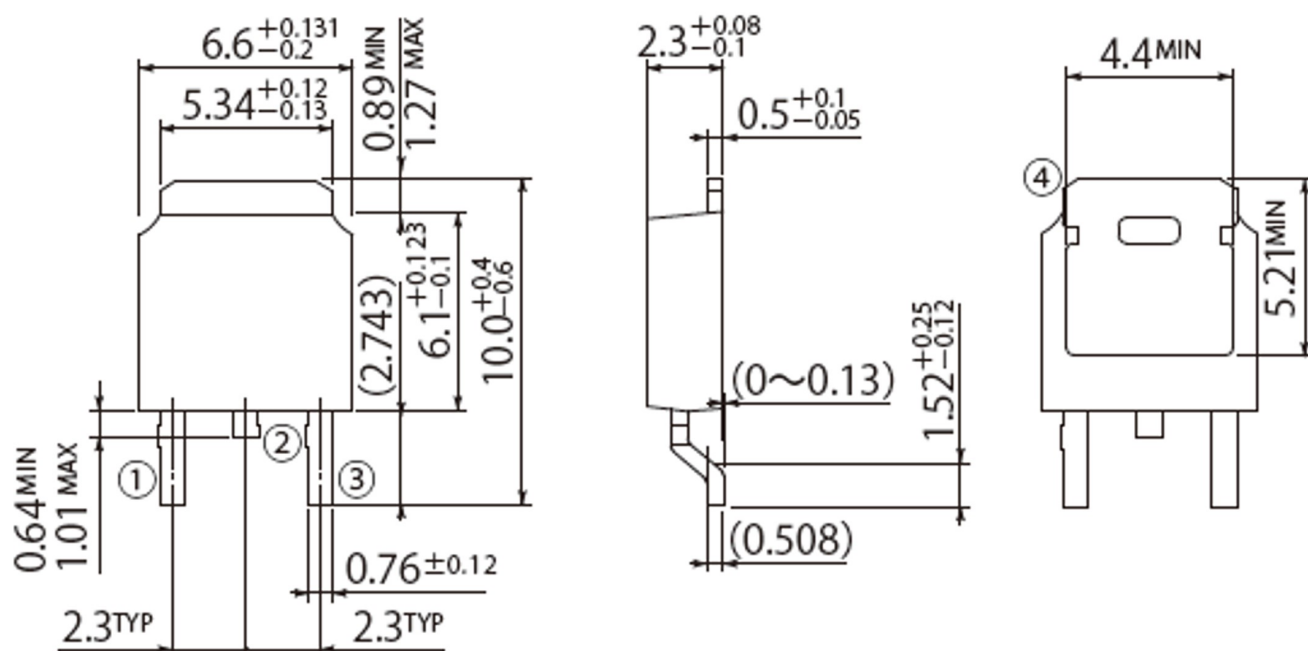


Single Avalanche Current vs Inductive Load



G2

|            |          |
|------------|----------|
| JEDEC Code | TO-252AA |
| JEITA Code | -        |
| House Name | FB       |



Referential Soldering Pad

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